

In re the Application of: MIMINO, Yutaka et al.

Group Art Unit: 2818

Serial No.: 10/090,610

Examiner: T. HO

Filed: March 6, 2002

P.T.O. Confirmation No.: 4961

For. HIGH FREQUENCY SEMICONDUCTOR DEVICE

## INFORMATION DISCLOSURE STATEMENT AND STATEMENT PURSUANT TO 37 CFR 1.97(d)

Attn: Group Director

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

July 16, 2003

Sir:

The attention of the Patent and Trademark Office is hereby directed to the document listed on the attached Form PTO-1449. One copy of the document is attached, together with a copy of an Office Action in the corresponding Taiwanese patent application.

This Information Disclosure Statement is submitted after the mailing of a final action, a Notice of Allowance, or an action that otherwise closes prosecution in the application, but on or before payment of the Issue Fee.

The undersigned hereby certifies that no item of information contained in this statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the undersigned after making reasonable inquiry, no information contained in this statement was known to any individual designated in 37 CFR § 1.56(c) more than three months prior to the filing of this statement.

The above information is presented so that the Patent and Trademark Office can, in the first instance, determine any materiality thereof to the claimed invention. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the documents cited in the attached Form PTO-1449 be made of record therein and appear on the first page of any patent to issue therefrom.

A check is attached hereto which covers the \$180.00 fee set forth in 37 CFR § 1.17(p). The Commissioner is hereby authorized to charge any additional fee (or credit any overpayment) associated with this Statement to our Deposit Account No. 01-2340.

Respectfully submitted,

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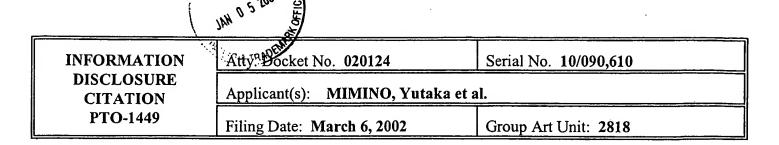
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PATENT TRADEMARK OFFICE

Enclosure:

Office Action on the corresponding Taiwanese patent application w/one reference

\$180.00 fee



## U.S. PATENT DOCUMENTS

Examiner Initial		Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
	AA						
	AB						
	AC						
	AD						
	AE						

## FOREIGN PATENT DOCUMENTS

	Document No.	Date	Country	Translation (Yes or No)
	AF			
	AG			
	AH			
<b> </b>	AI			
	AJ			

## **OTHER DOCUMENTS**

·	AK AL	Ali M. Niknejad and Robert G. Meyer: "Analysis, Design, and Optimization of Spiral Inductors and Transformers for Si RF IC's", IEEE Journal of Solid-State Circuits, Vol. 33, No. 10, October 1998.
Examiner	1	Date Considered